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PC714VxNSZX Series

DIP 6 pin General Purpose Photocoupler



■ Description

PC714VxNSZX Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 6 pin DIP.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V(*) and CTR is 50% to 600% at input current of 5mA.

■ Features

- 1. 6 pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}:80V(*))
- 4. High isolation voltage between input and output (V_{iso(rms)}: 5.0kV)
 - (*) Up to Date code "P7" (July 2002) V_{CEO} : 35V.

■ Agency approvals/Compliance

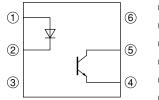
- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC714V)
- 2. Approved by TÜV (VDE0884) (as an option) file No. R-9151576 (as model No. **PC714V**)
- 3. Package resin: UL flammability grade (94V-0)

■ Applications

- 1. Home appliances
- 2. Programmable controllers
- 3. Personal computer peripherals



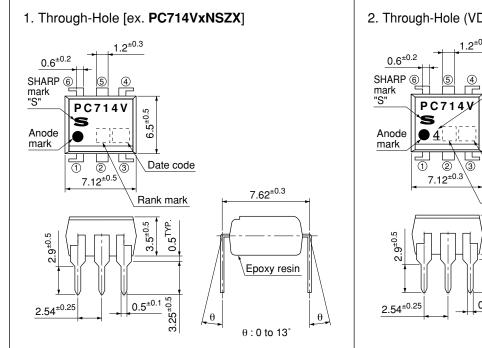
■ Internal Connection Diagram

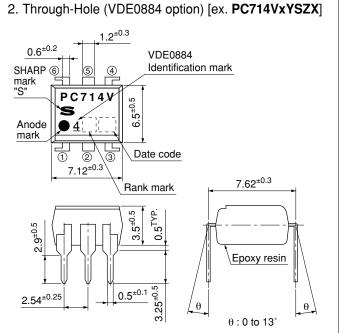


- 1 Anode
- ② Cathode
- 3 NC
- 4 Emitter
- ⑤ Collector
- 6 NC

■ Outline Dimensions

(Unit: mm)





Product mass: approx. 0.36g



Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin Japan

Rank mark
Refer to the Model Line-up



■ Absolute Maximum Ratings

	■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
	Parameter	Symbol	Rating	Unit				
	Forward current	I_{F}	50	mA				
Input	*1 Peak forward current	I_{FM}	1	A				
	Reverse voltage	V_R	6	V				
	Power dissipation	P	70	mW				
Output	Collector-emitter voltage	V_{CEO}	*4 80	V				
	Emitter-collector voltage	V_{ECO}	6	V				
	Collector current	I_{C}	50	mA				
	Collector power dissipation	P_{C}	150	mW				
Total power dissipation		P_{tot}	170	mW				
Operating temperature		Topr	-25 to +100	°C				
Storage temperature		T_{stg}	-40 to +125	°C				
*2 Isolation voltage		V _{iso (rms)}	5	kV				
*3 Soldering temperature		T_{sol}	260	°C				

^{*1} Pulse width≤100µs, Duty ratio: 0.001 *2 40 to 60%RH, AC for 1minute, f=60Hz *3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

	•						
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage		V_F	I _F =20mA	-	1.2	1.4	V
Peak forward voltage		V_{FM}	I _{FM} =0.5A	_	-	3.0	V
Reverse current		I_R	$V_R=4V$	_	_	10	μΑ
Terminal capacitance		C_t	V=0, f=1kHz	_	30	250	pF
Collector dark current		I_{CEO}	V_{CE} =50V, I_F =0	-	-	100	nA
Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	*5 80	-	-	V
Emitter-collector breakdown voltage		BV_{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	_	V
Current transfer ratio		I_{C}	$I_F=5mA, V_{CE}=5V$	2.5	-	30.0	mA
Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=20mA$, $I_C=1mA$	_	0.1	0.2	V
Isolation resistance		R_{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
Floating capacitance		$C_{\rm f}$	V=0, $f=1MHz$	-	0.6	1.0	pF
Cut-off frequency		f_C	V_{CE} =5V, I_{C} =2mA, R_{L} =100 Ω -3dB	_	80	_	kHz
Response time	Rise time	t_r	V 2V I 2m A D 1000	-	4	18	μs
	Fall time	t_{f}	$\mathbf{v}_{\text{CE}}=2\mathbf{v}, \mathbf{i}_{\text{C}}=2\text{IIIA}, \mathbf{K}_{\text{L}}=100\mathbf{S}2$	_	3	18	μs
	Forward volta Peak forward Reverse curre Terminal capa Collector dark Collector-emitter brea Emitter-collector brea Current transf Collector-emitter satu Isolation resis Floating capac Cut-off freque	Forward voltage Peak forward voltage Reverse current Terminal capacitance Collector dark current Collector-emitter breakdown voltage Emitter-collector breakdown voltage Current transfer ratio Collector-emitter saturation voltage Isolation resistance Floating capacitance Cut-off frequency Response time	Forward voltage V_F Peak forward voltage V_{FM} Reverse current I_R Terminal capacitance C_t Collector dark current I_{CEO} Collector-emitter breakdown voltage BV_{CEO} Emitter-collector breakdown voltage BV_{ECO} Current transfer ratio I_C Collector-emitter saturation voltage $V_{CE (sat)}$ Isolation resistance R_{ISO} Floating capacitance C_f Cut-off frequency f_C Response time I_C	Forward voltage V_F $I_F=20mA$ Peak forward voltage V_{FM} $I_{FM}=0.5A$ Reverse current I_R $V_R=4V$ Terminal capacitance C_t $V=0, f=1kHz$ Collector dark current I_{CEO} $V_{CE}=50V, I_F=0$ Collector-emitter breakdown voltage BV_{CEO} $I_C=0.1mA, I_F=0$ Emitter-collector breakdown voltage BV_{ECO} $I_E=10\mu A, I_F=0$ Current transfer ratio I_C $I_F=5mA, V_{CE}=5V$ Collector-emitter saturation voltage V_{CE} (sat) $I_F=20mA, I_C=1mA$ Isolation resistance R_{ISO} $DC500V, 40$ to $60\%RH$ Floating capacitance C_f $V=0, f=1MHz$ Cut-off frequency f_C $V_{CE}=5V, I_C=2mA, R_L=100\Omega$ $-3dB$ Response time R_{ISO} R_{I	Forward voltage V_F $I_F=20mA$ $-$ Peak forward voltage V_{FM} $I_{FM}=0.5A$ $-$ Reverse current I_R $V_R=4V$ $-$ Terminal capacitance C_t $V=0,f=1kHz$ $-$ Collector dark current I_{CEO} $V_{CE}=50V,I_F=0$ $-$ Collector-emitter breakdown voltage V_{CE} $V_{CE}=50V,I_F=0$ $V_{CE}=1000$ $V_{CE}=10$	Forward voltage V_F $I_F=20mA$ $ 1.2$ $I_{FM}=0.5A$ $ -$ Reverse current I_R $V_R=4V$ $ -$ Terminal capacitance C_t $V=0,f=1kHz$ $ 30$ $ -$ Collector dark current I_{CEO} $V_{CE}=50V,I_F=0$ $ -$ Collector-emitter breakdown voltage BV_{CEO} I_{CEO} $I_$	Forward voltage V_F $I_F=20mA$ - 1.2 1.4 Peak forward voltage V_{FM} $I_{FM}=0.5A$ - - 3.0 Reverse current I_R $V_R=4V$ - - 10 Terminal capacitance C_t $V=0, f=1kHz$ - 30 250 Collector dark current I_{CEO} $V_{CE}=50V, I_F=0$ - - 100 Collector emitter breakdown voltage BV_{CEO} $I_{C=0.1mA}, I_F=0$ *5 80 - - Emitter-collector breakdown voltage BV_{CEO} $I_{E}=10\mu A, I_F=0$ 6 - - Current transfer ratio I_{C} $I_{F}=5mA, V_{CE}=5V$ 2.5 - 30.0 Collector-emitter saturation voltage V_{CE} (sat) $I_{F}=20mA, I_{C}=1mA$ - 0.1 0.2 Isolation resistance R_{ISO} $DC500V, 40 to 60\% RH$ 5×10^{10} 1×10^{11} - Floating capacitance C_f $V=0, f=1MHz$ - 0.6 1.0 Cut-off freq

^{*5} Up to Date code "P7" (July 2002) BV_{CEO}≥35V.

^{*4} Up to Date code "P7" (July 2002) V_{CEO}: 35V.



■ Model Line-up

Lead Form	Throug	h-Hole			
Package	Sle	eve	Rank mark	I_{C} [mA] $(I_{F}=5$ mA, $V_{CE}=5$ V, $T_{a}=25$ °C)	
	50pcs/	'sleeve			
VDE0884		Approved			
Model No.	PC714V0NSZX	PC714V0YSZX	with or with out	2.5 to 30.0	
	PC714V1NSZX	PC714V1YSZX	A	4.0 to 8.0	
	PC714V2NSZX	PC714V2YSZX	В	6.5 to 13.0	
	PC714V3NSZX	PC714V3YSZX	С	10.0 to 20.0	
	PC714V5NSZX	PC714V5YSZX	A or B	4.0 to 13.0	
	PC714V6NSZX	PC714V6YSZX	B or C	6.5 to 20.0	
	PC714V8NSZX	PC714V8YSZX	A, B or C	4.0 to 20.0	

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.



Fig.1 Forward Current vs. Ambient Temperature

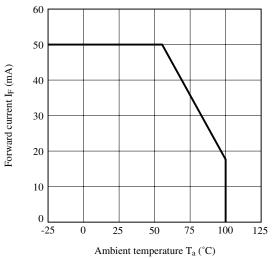


Fig.3 Collector Power Dissipation vs.
Ambient Temperature

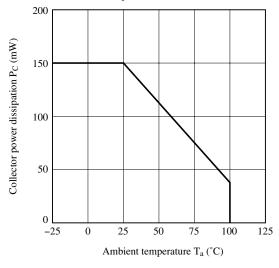


Fig.5 Peak Forward Current vs. Duty Ratio

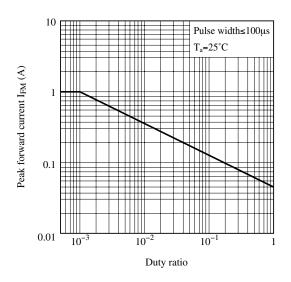


Fig.2 Diode Power Dissipation vs. Ambient Temperature

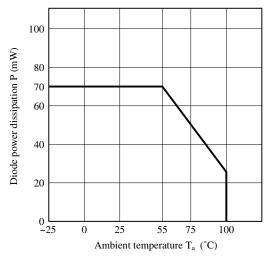


Fig.4 Total Power Dissipation vs. Ambient Temperature

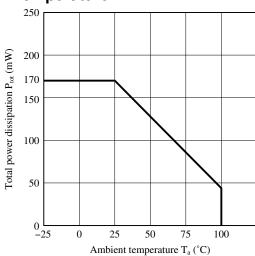


Fig.6 Forward Current vs. Forward Voltage

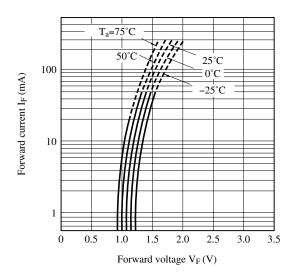




Fig.7 Current Transfer Ratio vs. Forward Current

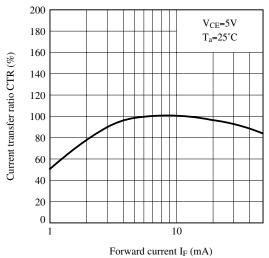


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

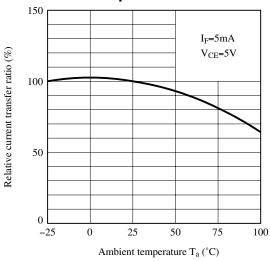


Fig.11 Collector Dark Current vs. Ambient Temperature

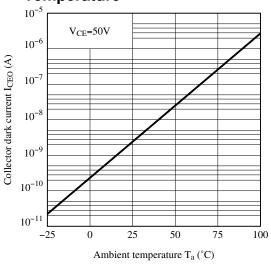


Fig.8 Collector Current vs. Collectoremitter Voltage

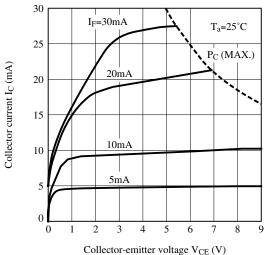


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

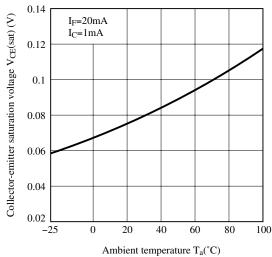
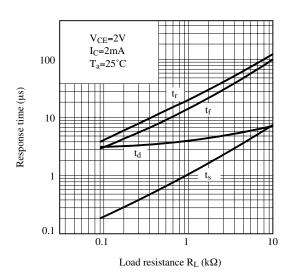


Fig.12 Response Time vs. Load Resistance



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Fig.13 Test Circuit for Response Time

V_{CC} Input Output Output 10%

Please refer to the conditions in Fig.12

Fig.14 Frequency Response

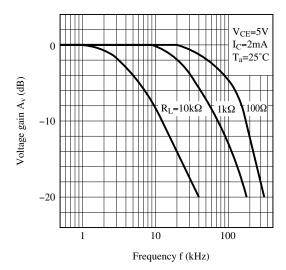
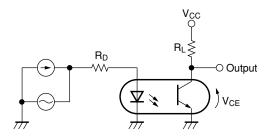


Fig.15 Test Circuit for Frequency Response



Please refer to the conditions in Fig.14

Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

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[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

Soldering Method

Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

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Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.



■ Package specification

Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

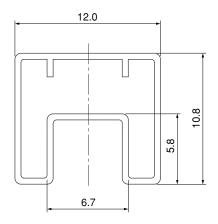
MAX. 50 pcs. of products shall be packaged in a sleeve.

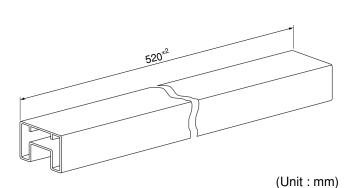
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabbed stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions







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 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
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- --- Alarm equipment
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